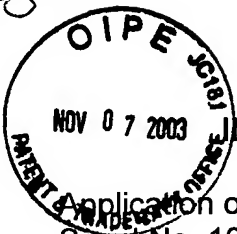


Image

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MEMC 98-3052 (2512.2)
PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster
Serial No. 10/038,084
Filed January 03, 2002
Confirmation No. 7363
For SILICON ON INSULATOR STRUCTURE HAVING A LOW DEFECT DENSITY
DEVICE LAYER AND A PROCESS FOR THE PREPARATION THEREOF
Examiner Anh D. Mai

Art Unit 2814

November 7, 2003

AMENDMENT B

TO THE COMMISSIONER FOR PATENTS,

SIR:

In response to the Office action dated May 7, 2003, please make the following amendments and consider the following remarks and arguments:

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.